TOSHIBA Diode Epitaxial Schottky Barrier Type

HN2S05FU

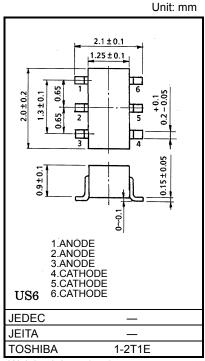
High-Speed Switching Applications

- The HN2S05FU is composed of three (3) independent diodes.
- Excellent forward current and forward voltage characteristics:
 V_F = 0.23 V (typ.) @ IF = 5 mA

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Maximum (peak) reverse voltage	V_{RM}	15	V
Reverse voltage	V _R	10	V
Maximum (peak) forward current	I _{FM}	200 *	mA
Average forward current	I _O	100 *	mA
Surge current (10 ms)	I _{FSM}	1 *	Α
Power dissipation	Р	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C
Operating temperature range	T _{opr}	− 40~110	°C

^{* :} This is the maximum rating for a single diode (Q1, Q2 or Q3). Where two or three diodes are used, the maximum rating per diode is 75% that for a single diode.

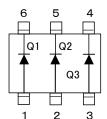


Weight: 6.2 mg (typ.)

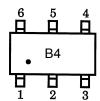
Electrical Characteristics (Q1, Q2, Q3 Common, Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward voltage	V _{F (1)}	I _F = 1 mA	_	0.18	_	V
	V _{F (2)}	I _F = 5 mA	_	0.23	0.30	
	V _{F (3)}	I _F = 100 mA	_	0.35	0.50	
Reverse current	I _R	V _R = 10 V	_	_	20	μΑ
Total capacitance	C _T	V _R = 0, f = 1 MH _z	_	5	_	pF

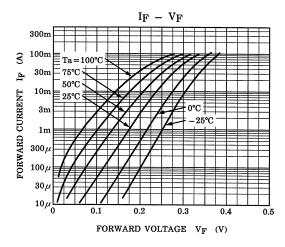
Pin Assignment (top view)

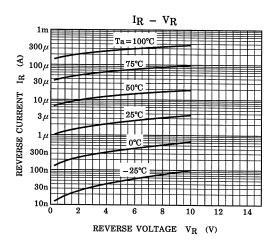


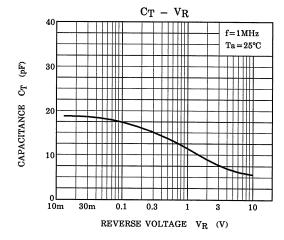
Marking

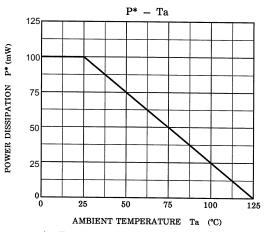


^{** :}Total rating









* : Total Rating

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